

## 39 $\mu$ A Micropower Single and Dual Rail-to-Rail Input-Output Low Input Bias Current (RRIO) Op Amps

The ISL28166 and ISL28266 are micropower precision operational amplifiers optimized for single supply operation at 5V and can operate down to 2.4V.

These devices feature an Input Range Enhancement Circuit (IREC), which enables them to maintain CMRR performance for input voltages greater than the positive supply. The input signal is capable of swinging 0.5V above a 5.0V supply (0.25 for a 2.5V supply) and to within 10mV from ground. The output operation is rail-to-rail.

The 1/f corner of the voltage noise spectrum is at 1kHz. This results in low frequency noise performance, which can only be found on devices with an order of magnitude higher than the supply current.

ISL28166 and ISL28266 can be operated from one lithium cell or two Ni-Cd batteries. The input range includes both positive and negative rail. The output swings to both rails.

### Ordering Information

PART NUMBER (Note)	PART MARKING	PACKAGE (Pb-free)	PKG. DWG. #
ISL28166FHZ-T7*	GABY	6 Ld SOT-23	MDP0038
Coming Soon ISL28266FUZ	8266Z	8 Ld MSOP	MDP0043
Coming Soon ISL28266FUZ-T7*	8266Z	8 Ld MSOP	MDP0043
Coming Soon ISL28266FBZ	28266 FBZ	8 Ld SOIC	MDP0027
Coming Soon ISL28266FBZ-T7*	28266 FBZ	8 Ld SOIC	MDP0027

\*Please refer to TB347 for details on reel specifications.

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate PLUS ANNEAL - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

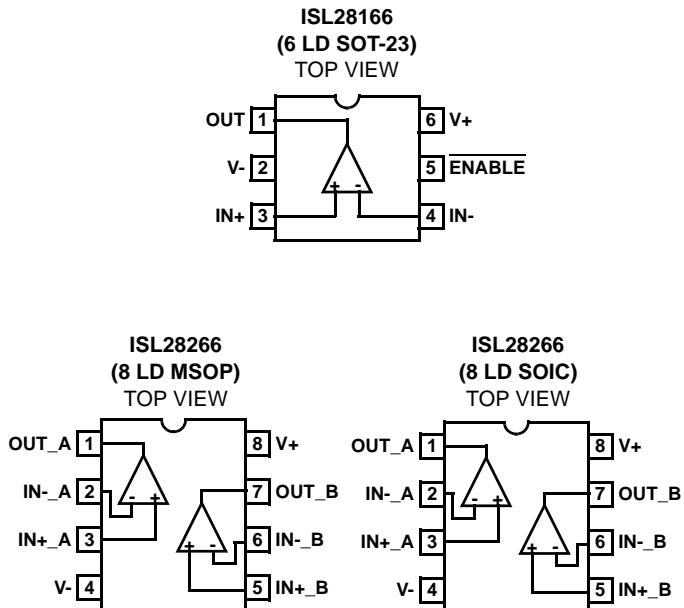
### Features

- 39 $\mu$ A typical supply current
- 5nA max input bias current
- 250kHz gain bandwidth product ( $A_V = 1$ )
- 2.4V to 5V single supply voltage range
- Rail-to-rail input and output
- Enable pin (ISL28166 only)
- Pb-free (RoHS compliant)

### Applications

- Battery- or solar-powered systems
- 4mA to 20mA current loops
- Handheld consumer products
- Medical devices
- Sensor amplifiers
- ADC buffers
- DAC output amplifiers

### Pinouts



**Absolute Maximum Ratings** ( $T_A = +25^\circ\text{C}$ )

Supply Voltage.....	5.5V
Supply Turn-on Voltage Slew Rate .....	1V/ $\mu\text{s}$
Differential Input Current .....	5mA
Differential Input Voltage .....	0.5V
Input Voltage .....	V <sub>-</sub> - 0.5V to V <sub>+</sub> + 0.5V
ESD Rating	
Human Body Model .....	3kV
Machine Model.....	300V

**Thermal Information**

Thermal Resistance (Typical Note 1)	$\theta_{JA}$ ( $^\circ\text{C}/\text{W}$ )
6 Ld SOT-23 Package .....	230
8 Ld MSOP Package .....	160
8 Ld SOIC Package .....	115
Output Short-Circuit Duration .....	Indefinite
Ambient Operating Temperature Range .....	-40 $^\circ\text{C}$ to +125 $^\circ\text{C}$
Storage Temperature Range .....	-65 $^\circ\text{C}$ to +150 $^\circ\text{C}$
Operating Junction Temperature .....	+125 $^\circ\text{C}$
Pb-free reflow profile .....	see link below <a href="http://www.intersil.com/pbfree/Pb-FreeReflow.asp">http://www.intersil.com/pbfree/Pb-FreeReflow.asp</a>

**CAUTION:** Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

**NOTE:**

1.  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

**IMPORTANT NOTE:** All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$

**Electrical Specifications**     $V_+ = 5\text{V}$ ,  $V_- = 0\text{V}$ ,  $V_{CM} = 2.5\text{V}$ ,  $T_A = +25^\circ\text{C}$  unless otherwise specified. **Boldface limits apply over the operating temperature range, -40 $^\circ\text{C}$  to +125 $^\circ\text{C}$ .** Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 2)	TYP	MAX (Note 2)	UNIT
$V_{OS}$	Input Offset Voltage	6 Ld SOT-23	-600 <b>-600</b>	-7	600 <b>600</b>	$\mu\text{V}$
$\frac{\Delta V_{OS}}{\Delta T}$	Input Offset Drive vs Temperature			1.5		$\mu\text{V}/^\circ\text{C}$
$I_{OS}$	Input Offset Current		-1.5 <b>-5</b>	0.34	1.2 <b>2.5</b>	nA
$I_B$	Input Bias Current		-2 <b>-3.5</b>	1.14	5 <b>5</b>	nA
$E_N$	Input Noise Voltage Density	$F_O = 1\text{kHz}$		46		$\text{nV}/\sqrt{\text{Hz}}$
$I_N$	Input Noise Current Density	$F_O = 1\text{kHz}$		0.14		$\text{pA}/\sqrt{\text{Hz}}$
CMIR	Input Common-Mode Voltage Range		0		5	V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0\text{V}$ to $5\text{V}$	80 <b>75</b>	110		dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.4\text{V}$ to $5\text{V}$	90 <b>75</b>	104		dB
$A_{VOL}$	Large Signal Voltage Gain	$V_O = 0.5\text{V}$ to $4.5\text{V}$ , $R_L = 100\text{k}\Omega$	200 <b>175</b>	412		$\text{V}/\text{mV}$
		$V_O = 0.5\text{V}$ to $4.5\text{V}$ , $R_L = 1\text{k}\Omega$	35 <b>30</b>	70		$\text{V}/\text{mV}$
$V_{OUT}$	Maximum Output Voltage Swing	Output low, $R_L = 100\text{k}\Omega$		3	6 <b>8</b>	$\text{mV}$
		Output low, $R_L = 1\text{k}\Omega$		130	150 <b>200</b>	$\text{mV}$
		Output high, $R_L = 100\text{k}\Omega$	4.992 <b>4.99</b>	4.995		V
		Output high, $R_L = 1\text{k}\Omega$	4.85 <b>4.8</b>	4.88		V
SR	Slew Rate			0.05		$\text{V}/\mu\text{s}$
GBW	Gain Bandwidth Product	$A_V = 1$		250		kHz
$I_{S,ON}$	Supply Current, Enabled		29 <b>18</b>	39	47 <b>56</b>	$\mu\text{A}$
$I_{S,OFF}$	Supply Current, Disabled			10	14 <b>16</b>	$\mu\text{A}$

**Electrical Specifications**  $V_+ = 5V$ ,  $V_- = 0V$ ,  $V_{CM} = 2.5V$ ,  $T_A = +25^\circ C$  unless otherwise specified. **Boldface limits apply over the operating temperature range,  $-40^\circ C$  to  $+125^\circ C$ .** Temperature data established by characterization. **(Continued)**

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 2)	TYP	MAX (Note 2)	UNIT
$I_{O+}$	Short-Circuit Output Current	$R_L = 10\Omega$	28 <b>23</b>	31		mA
$I_{O-}$	Short-Circuit Output Current	$R_L = 10\Omega$	24 <b>18</b>	26		mA
$V_{SUPPLY}$	Supply Operating Range	Guaranteed by PSRR test	2.4		5	V
$V_{INH}$	Enable Pin High Level			<b>2</b>		V
$V_{INL}$	Enable Pin Low Level				<b>0.8</b>	V
$I_{ENH}$	Enable Pin Input Current	$V_{EN} = 5V$		1	1.2 <b>1.2</b>	$\mu A$
$I_{ENL}$	Enable Pin Input Current	$V_{EN} = 0V$		16	25 <b>30</b>	nA
$t_{EN}$	Enable to output on-state delay time (ISL28166)	$V_{OUT} = 1V$ (enable state); $V_{EN} = \text{High to Low}$		10.8		$\mu s$
$t_{\bar{EN}}$	Enable to output off-state delay time (ISL28166)	$V_{OUT} = 0V$ (disabled state) $V_{EN} = \text{Low to High}$		0.1		$\mu s$

NOTE:

2. Parts are 100% tested at  $+25^\circ C$ . Temperature limits established by characterization and are not production tested.

### Typical Performance Curves

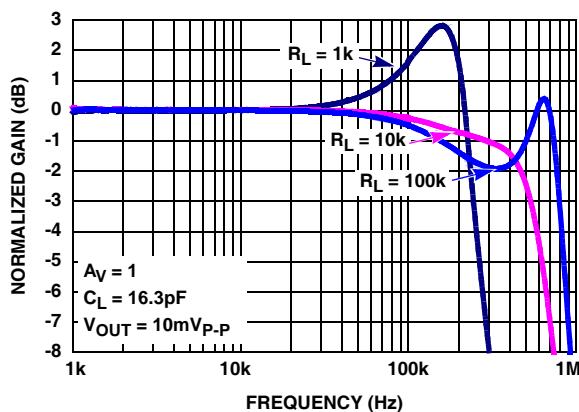


FIGURE 1. GAIN vs FREQUENCY vs  $R_L$

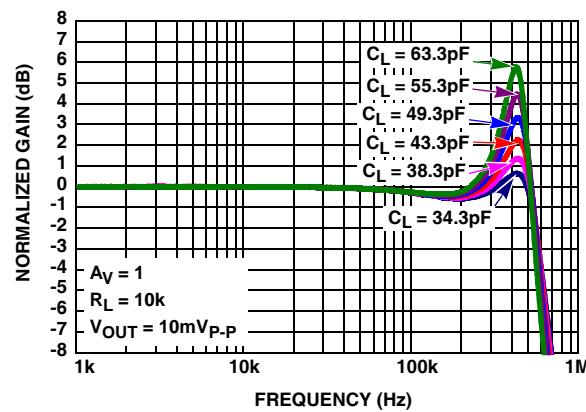


FIGURE 2. GAIN vs FREQUENCY vs  $C_L$

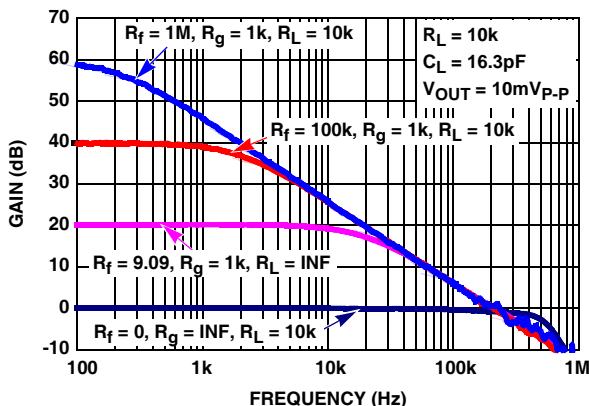


FIGURE 3. CLOSED LOOP GAIN vs FREQUENCY

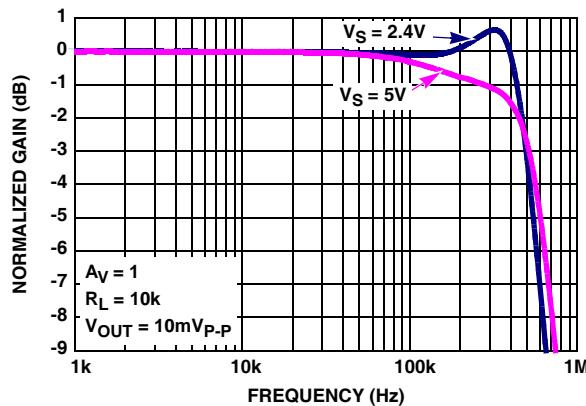
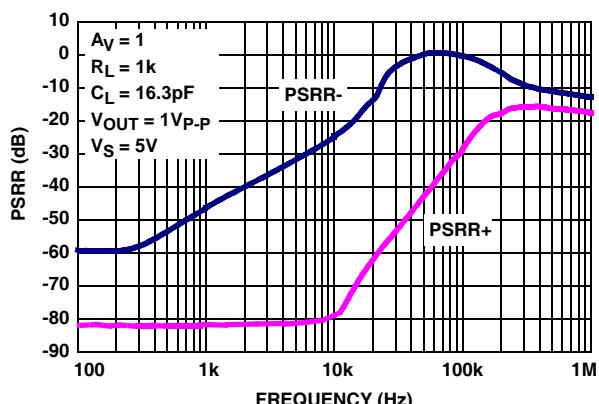
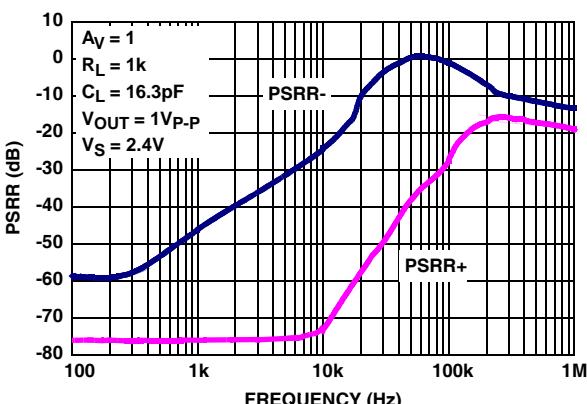
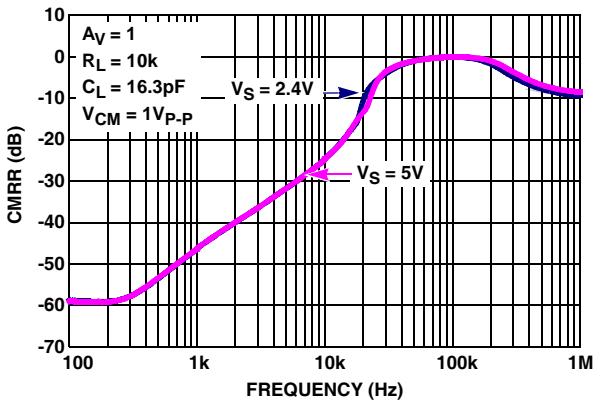
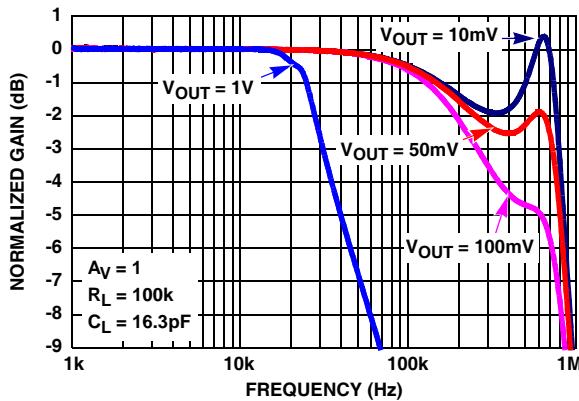
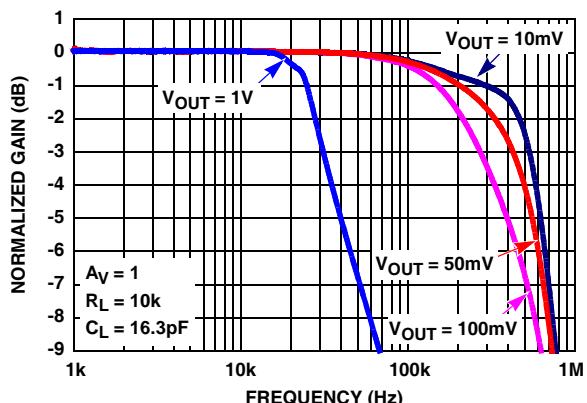
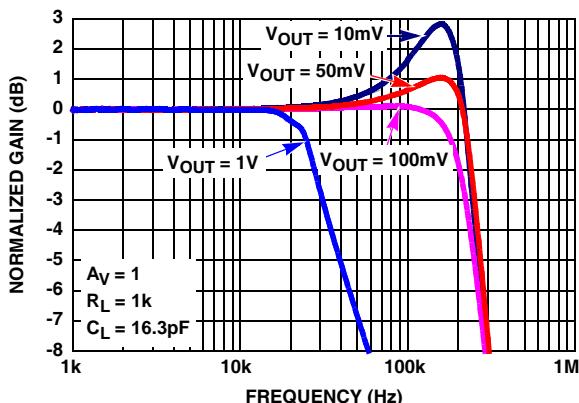


FIGURE 4. GAIN vs FREQUENCY vs  $V_S$

**Typical Performance Curves (Continued)**

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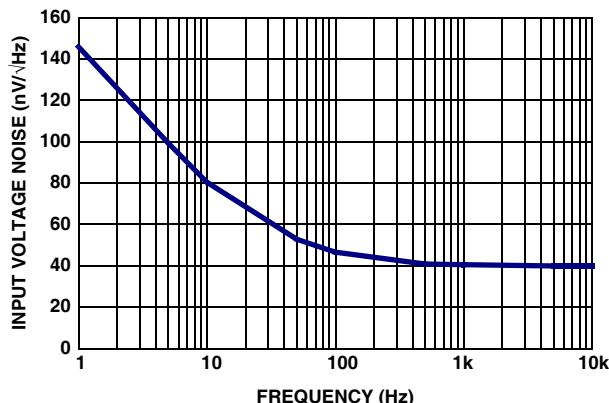


FIGURE 11. INPUT VOLTAGE NOISE vs FREQUENCY

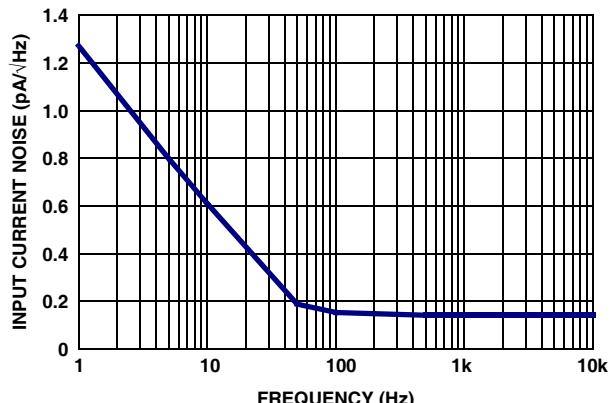


FIGURE 12. INPUT CURRENT NOISE vs FREQUENCY

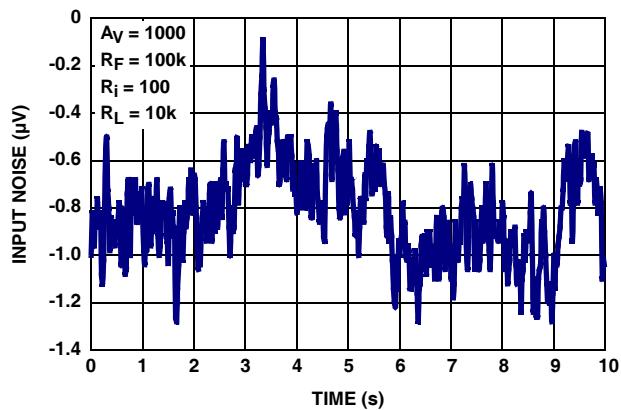


FIGURE 13. 1Hz TO 10Hz INPUT NOISE

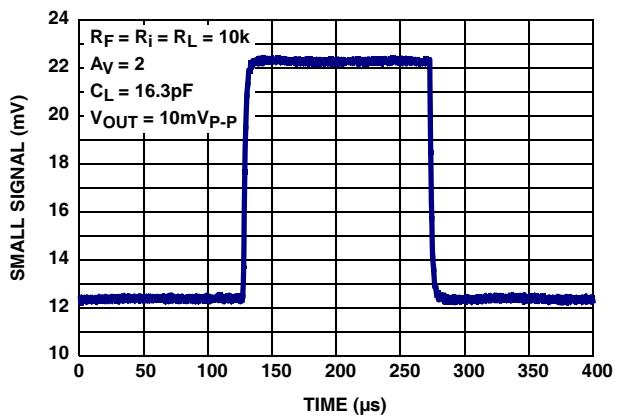


FIGURE 14. SMALL SIGNAL STEP RESPONSE

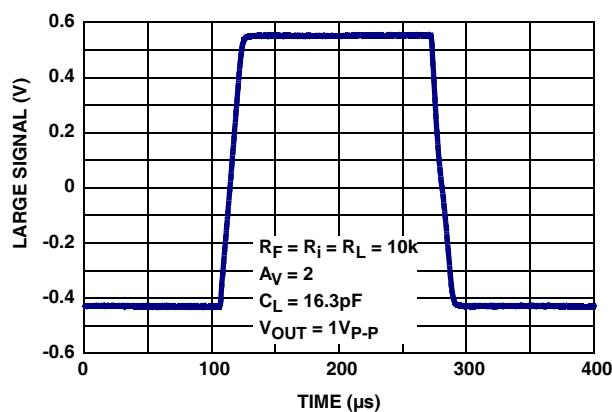


FIGURE 15. LARGE SIGNAL STEP RESPONSE

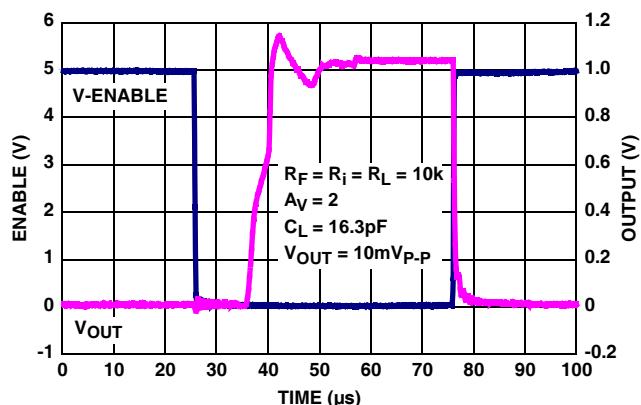
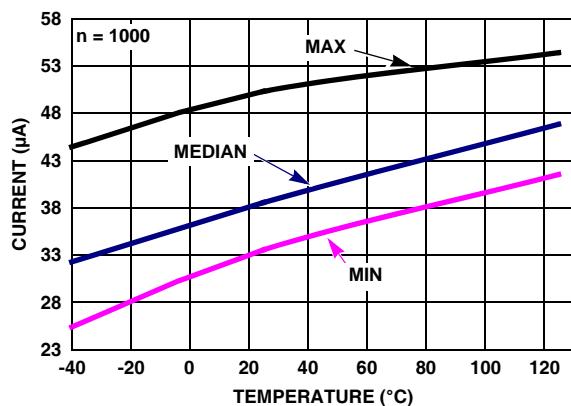
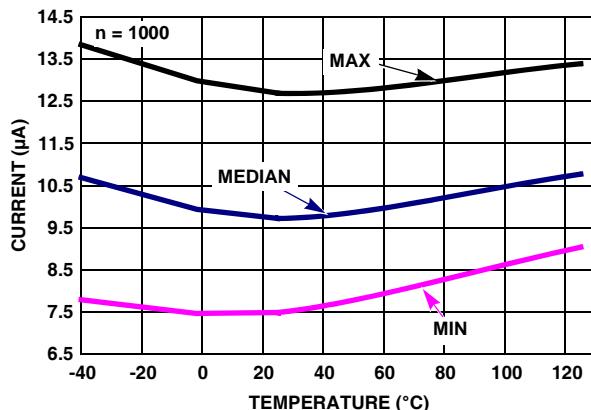


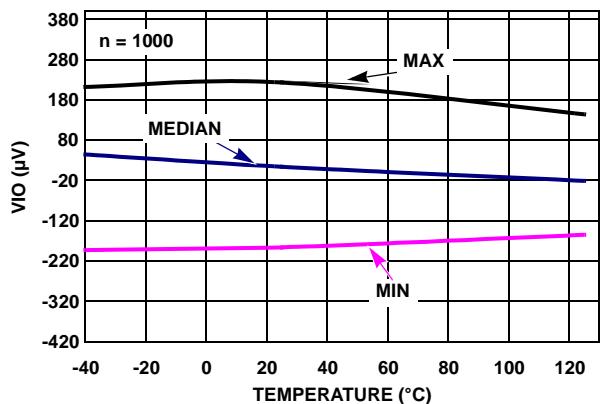
FIGURE 16. ENABLE TO OUTPUT DELAY

**Typical Performance Curves (Continued)**

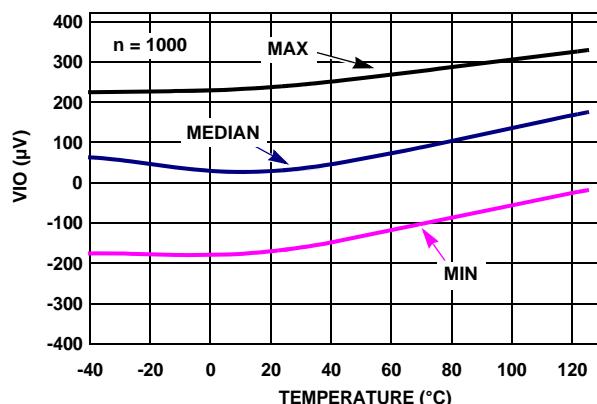
**FIGURE 17. SUPPLY CURRENT ENABLED vs TEMPERATURE,  $V_S = \pm 2.5\text{V}$**



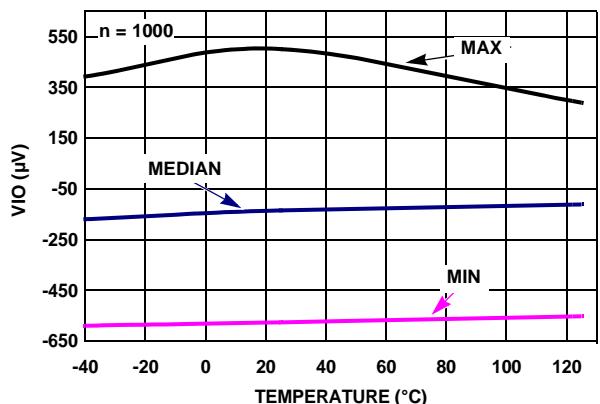
**FIGURE 18. SUPPLY CURRENT DISABLED vs TEMPERATURE,  $V_S = \pm 2.5\text{V}$**



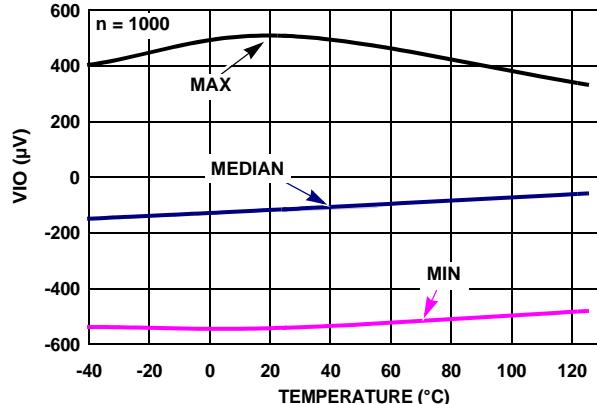
**FIGURE 19. VIO SO8 PACKAGE vs TEMPERATURE,  $V_S = \pm 2.5\text{V}$**



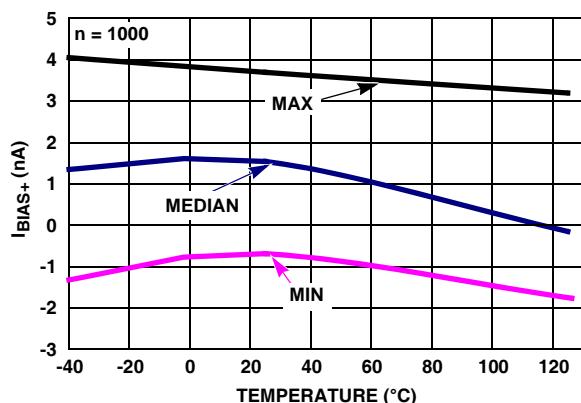
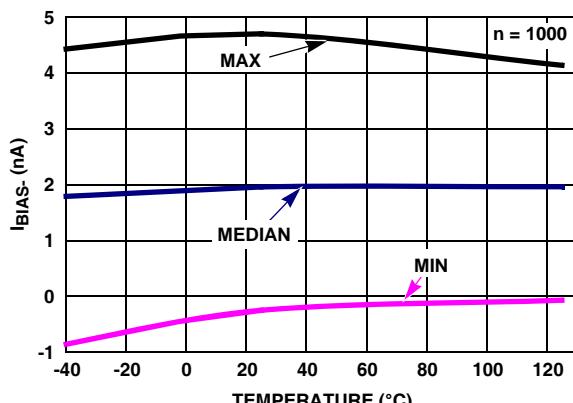
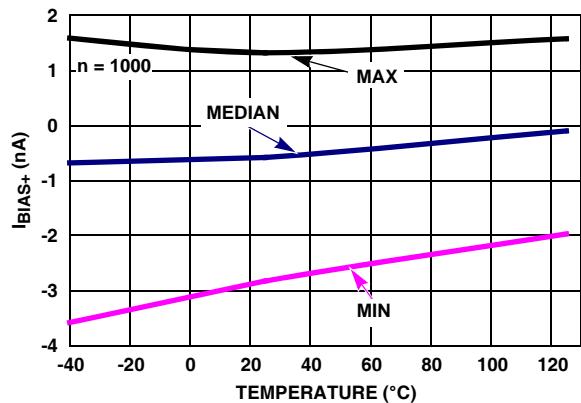
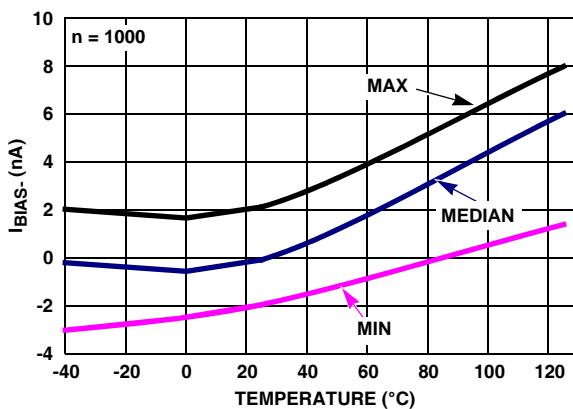
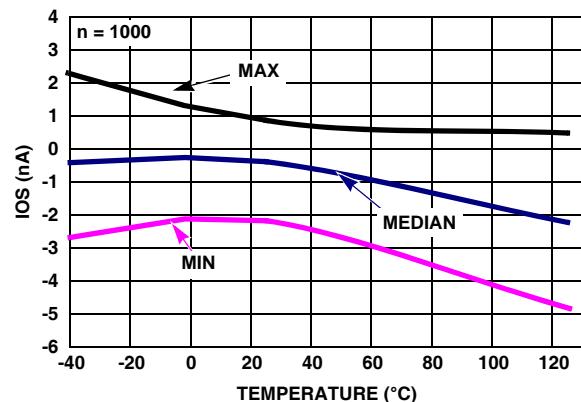
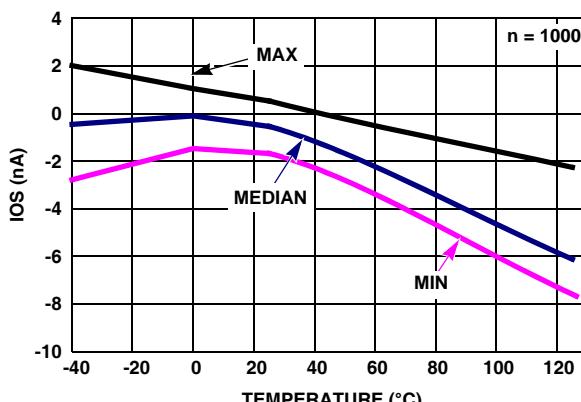
**FIGURE 20. VIO SO8 PACKAGE vs TEMPERATURE,  $V_S = \pm 1.2\text{V}$**

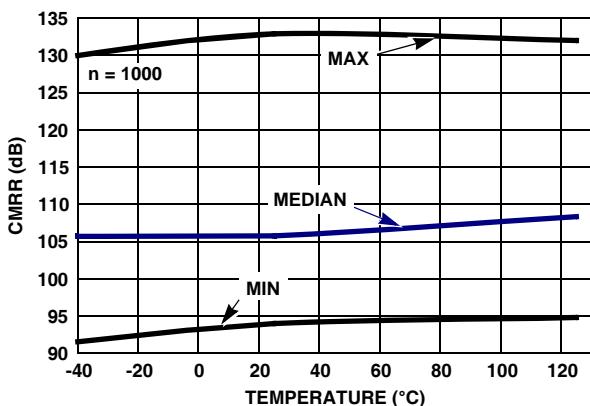
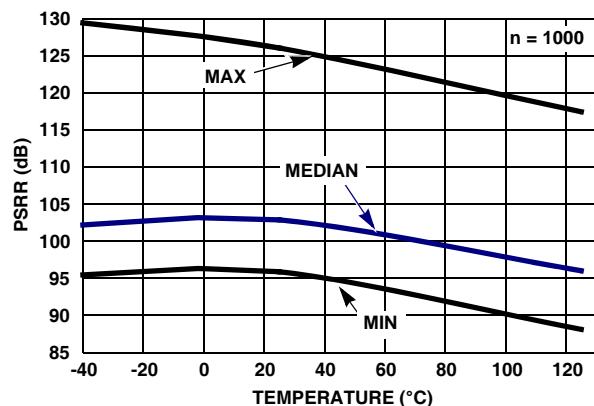
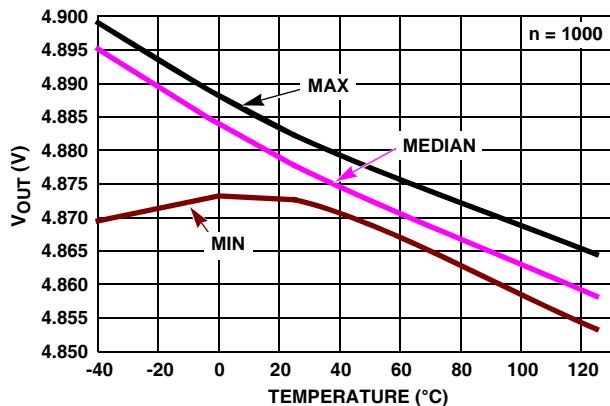
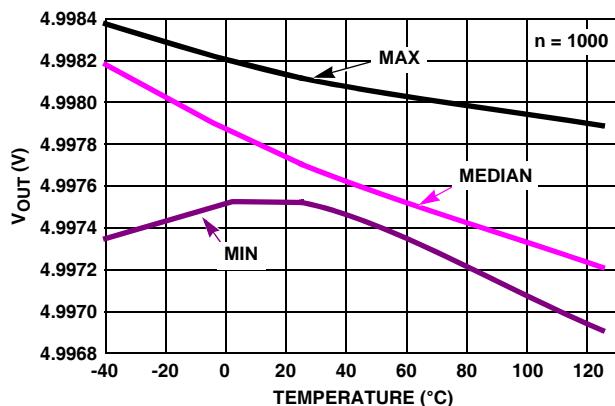
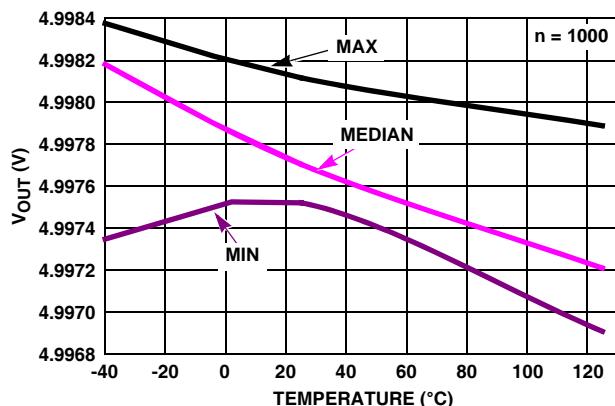
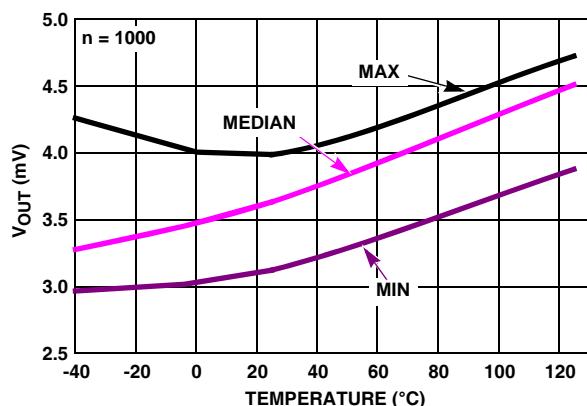


**FIGURE 21. VIO SOT-23 PACKAGE vs TEMPERATURE,  $V_S = \pm 2.5\text{V}$**

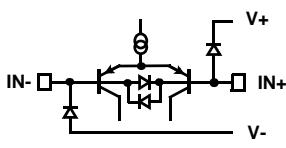
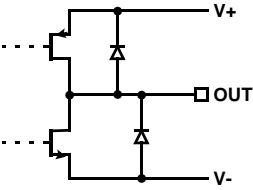
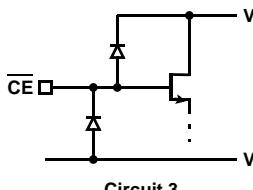


**FIGURE 22. VIO SOT-23 PACKAGE vs TEMPERATURE,  $V_S = \pm 1.2\text{V}$**

**Typical Performance Curves (Continued)**FIGURE 23.  $I_{BIAS+}$  vs TEMPERATURE,  $V_S = \pm 2.5V$ FIGURE 24.  $I_{BIAS-}$  vs TEMPERATURE,  $V_S = \pm 2.5V$ FIGURE 25.  $I_{BIAS+}$  vs TEMPERATURE,  $V_S = \pm 1.5V$ FIGURE 26.  $I_{BIAS-}$  vs TEMPERATURE,  $V_S = \pm 1.2V$ FIGURE 27. IOS vs TEMPERATURE,  $V_S = \pm 2.5V$ FIGURE 28. IOS vs TEMPERATURE,  $V_S = \pm 1.5V$

**Typical Performance Curves (Continued)**FIGURE 29. CMRR vs TEMPERATURE  $V_+ = \pm 2.5V, \pm 1.5V$ FIGURE 30. PSRR vs TEMPERATURE  $\pm 1.2V$  TO  $\pm 2.5V$ FIGURE 31.  $V_{OUT}$  HIGH vs TEMP  $V_S = \pm 2.5V$ ,  $R_L = 1k$ FIGURE 32.  $V_{OUT}$  HIGH  $V_S = \pm 2.5V$ ,  $R_L = 100k$ FIGURE 33.  $V_{OUT}$  LOW  $V_S = \pm 2.5V$ ,  $R_L = 1k$ FIGURE 34.  $V_{OUT}$  LOW  $V_S = \pm 2.5V$ ,  $R_L = 100k$

## Pin Descriptions

ISL28166 (6 Ld SOT-23)	ISL28266 (8 Ld SOIC) (8 Ld MSOP)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
4	2 (A) 6 (B)	IN- IN_A IN_B	Inverting input	 <p style="text-align: center;">Circuit 1</p>
3	3 (A) 5 (B)	IN+ IN+_A IN+_B	Non-inverting input	(See Circuit 1)
2	4	V-	Negative supply	
1	1 (A) 7 (B)	OUT OUT_A OUT_B	Output	 <p style="text-align: center;">Circuit 2</p>
6	8	V+	Positive supply	
5		ENABLE	Chip enable	 <p style="text-align: center;">Circuit 3</p>

## Applications Information

### Introduction

The ISL28166 is a single BiMOS rail-to-rail input, output (RRIO) operational amplifier with an enable feature. The ISL28266 is a dual version without the enable feature. Both devices are designed to operate from single supply (2.4V to 5.0V) or dual supplies ( $\pm 1.2V$  to  $\pm 2.5V$ ) while drawing only 39 $\mu A$  of supply current per amplifier. This combination of low power and precision performance makes this device suitable for a variety of low power applications including battery powered systems.

### Rail-to-Rail Input/Output

These devices feature bi-polar inputs which have an input common mode range that extends to the rails, and CMOS outputs that can typically swing to within about 4mV of the supply rails with a 100k $\Omega$  load. The NMOS sinks current to swing the output in the negative direction. The PMOS sources current to swing the output in the positive direction.

### Input Protection

All input terminals have internal ESD protection diodes to both positive and negative supply rails, limiting the input voltage to

within one diode beyond the supply rails. They also contain back-to-back diodes across the input terminals. For applications where the input differential voltage is expected to exceed 0.5V, external series resistors must be used to ensure the input currents never exceed 5mA (Figure 35).

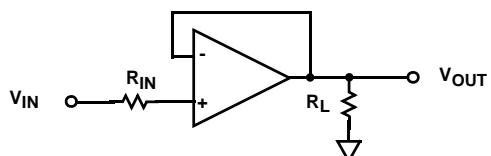


FIGURE 35. INPUT CURRENT LIMITING

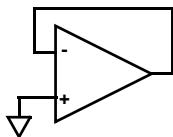
### Enable/Disable Feature

The ISL28166 offers an  $\overline{EN}$  pin that disables the device when pulled up to at least 2.0V. In the disabled state (output in a high impedance state), the part consumes typically 10 $\mu A$ . By disabling the part, multiple ISL28166 parts can be connected together as a MUX. In this configuration, the outputs are tied together in parallel and a channel can be selected by the  $\overline{EN}$  pin. The  $\overline{EN}$  pin also has an internal pull-down. If left open, the  $\overline{EN}$  pin will pull to the negative rail and the device will be enabled by default.

The loading effects of the feedback resistors of the disabled amplifier must be considered when multiple amplifier outputs are connected together.

### **Using Only One Channel**

The ISL28266 is a dual op amp. If the application only requires one channel, the user must configure the unused channel to prevent it from oscillating. The unused channel will oscillate if the input and output pins are floating. This will result in higher than expected supply currents and possible noise injection into the channel being used. The proper way to prevent this oscillation is to short the output to the negative input and ground the positive input (as shown in Figure 36).



**FIGURE 36. PREVENTING OSCILLATIONS IN UNUSED CHANNELS**

### **Current Limiting**

These devices have no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

### **Power Dissipation**

It is possible to exceed the +125°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature ( $T_{JMAX}$ ) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to remain in the safe operating area. These parameters are related in Equation 1:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} \times P_{MAXTOTAL}) \quad (\text{EQ. 1})$$

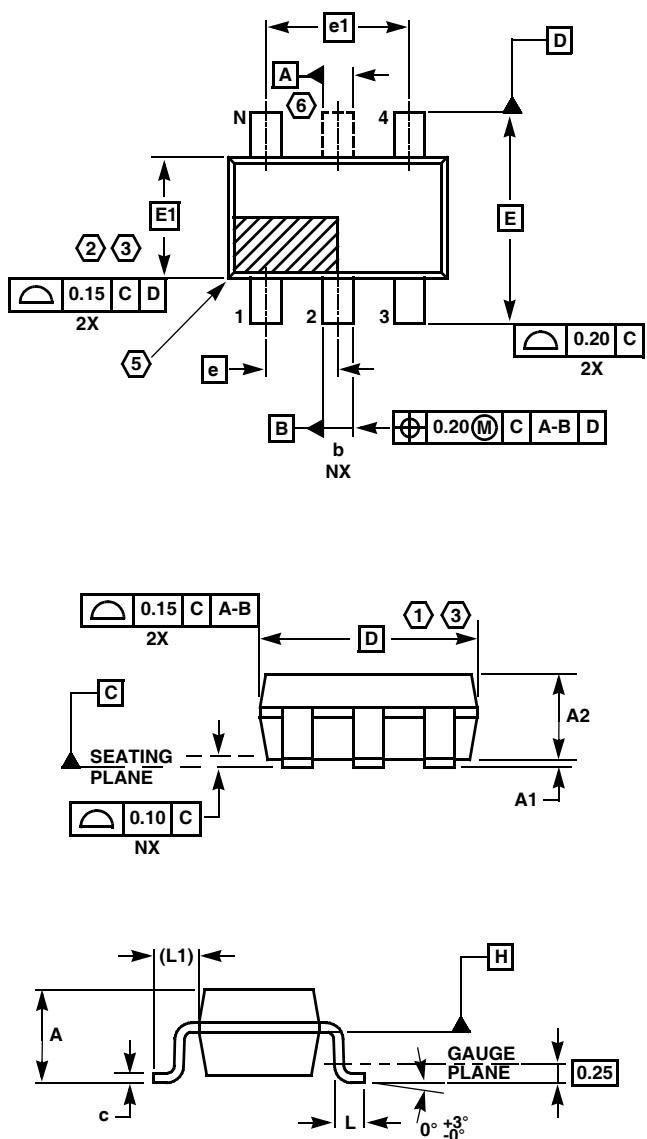
where:

- $P_{MAXTOTAL}$  is the sum of the maximum power dissipation of each amplifier in the package ( $P_{MAX}$ )
- $P_{MAX}$  for each amplifier can be calculated using Equation 2:

$$P_{MAX} = 2 \times V_S \times I_{SMAX} + (V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L} \quad (\text{EQ. 2})$$

where:

- $T_{MAX}$  = Maximum ambient temperature
- $\theta_{JA}$  = Thermal resistance of the package
- $P_{MAX}$  = Maximum power dissipation of 1 amplifier
- $V_S$  = Supply voltage
- $I_{MAX}$  = Maximum supply current of 1 amplifier
- $V_{OUTMAX}$  = Maximum output voltage swing of the application
- $R_L$  = Load resistance

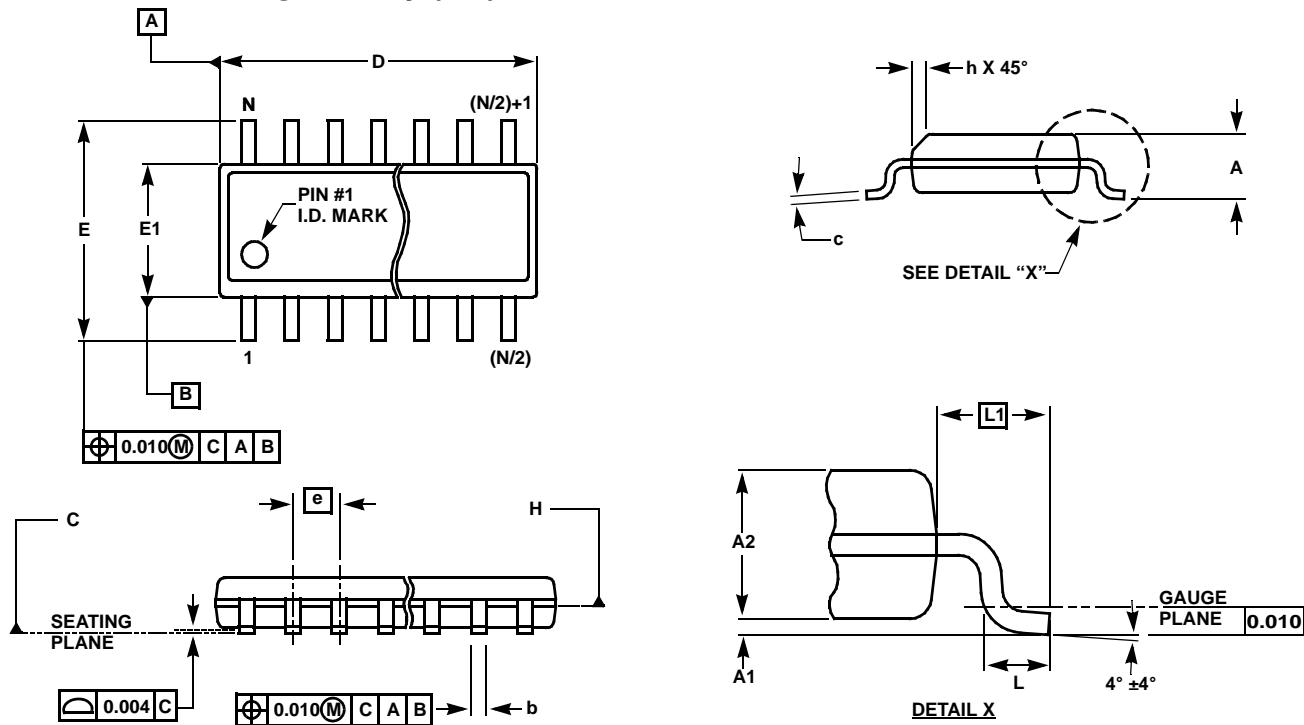
**SOT-23 Package Family****MDP0038****SOT-23 PACKAGE FAMILY**

SYMBOL	MILLIMETERS		TOLERANCE
	SOT23-5	SOT23-6	
A	1.45	1.45	MAX
A1	0.10	0.10	$\pm 0.05$
A2	1.14	1.14	$\pm 0.15$
b	0.40	0.40	$\pm 0.05$
c	0.14	0.14	$\pm 0.06$
D	2.90	2.90	Basic
E	2.80	2.80	Basic
E1	1.60	1.60	Basic
e	0.95	0.95	Basic
e1	1.90	1.90	Basic
L	0.45	0.45	$\pm 0.10$
L1	0.60	0.60	Reference
N	5	6	Reference

Rev. F 2/07

**NOTES:**

1. Plastic or metal protrusions of 0.25mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
3. This dimension is measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.
5. Index area - Pin #1 I.D. will be located within the indicated zone (SOT23-6 only).
6. SOT23-5 version has no center lead (shown as a dashed line).

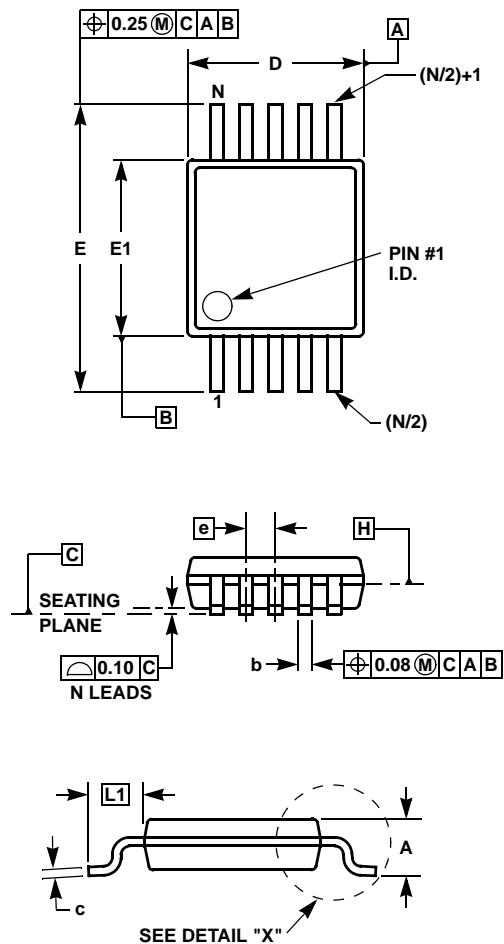
**Small Outline Package Family (SO)****MDP0027****SMALL OUTLINE PACKAGE FAMILY (SO)**

SYMBOL	INCHES							TOLERANCE	NOTES
	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)		
A	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
c	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
E	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
e	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
N	8	14	16	16	20	24	28	Reference	-

Rev. M 2/07

## NOTES:

1. Plastic or metal protrusions of 0.006" maximum per side are not included.
2. Plastic interlead protrusions of 0.010" maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994

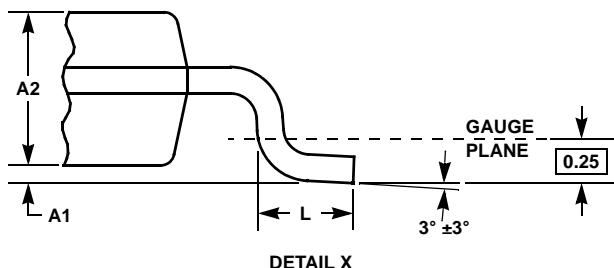
**Mini SO Package Family (MSOP)****MDP0043**  
**MINI SO PACKAGE FAMILY**

SYMBOL	MILLIMETERS		TOLERANCE	NOTES
	MSOP8	MSOP10		
A	1.10	1.10	Max.	-
A1	0.10	0.10	$\pm 0.05$	-
A2	0.86	0.86	$\pm 0.09$	-
b	0.33	0.23	+0.07/-0.08	-
c	0.18	0.18	$\pm 0.05$	-
D	3.00	3.00	$\pm 0.10$	1, 3
E	4.90	4.90	$\pm 0.15$	-
E1	3.00	3.00	$\pm 0.10$	2, 3
e	0.65	0.50	Basic	-
L	0.55	0.55	$\pm 0.15$	-
L1	0.95	0.95	Basic	-
N	8	10	Reference	-

Rev. D 2/07

## NOTES:

1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.



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